

We claim:

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13. The method of claim 9 further comprising adjusting said first noise band to a designated power level prior to said converting step.
14. The method of claim 13 wherein said converting step comprises inputting said adjusted first noise band into a frequency multiplier, wherein said designated power level is a maximum safe input power level of said frequency multiplier.
15. The method of claim 13 wherein said adjusting step comprises amplifying a power of said first noise band.
16. The method of claim 13 wherein said adjusting step comprises attenuating a power of said first noise band.
17. The method of claim 9 further comprising directing said second band of noise toward a destination.
18. A millimeter- and submillimeter-wave noise generating apparatus comprising:  
a microwave noise source for generating microwave noise;  
means for adjusting a power of said microwave noise source to a designated level; and  
a frequency multiplier for converting said adjusted microwave noise into millimeter- and submillimeter-wave noise, wherein said designated level is a maximum safe input level of said frequency multiplier.
19. The apparatus of claim 18 wherein said means for adjusting comprises one or more microwave amplifiers.
20. The apparatus of claim 19 wherein said means for adjusting further comprises a level-set attenuator.
21. The apparatus of claim 18 wherein said millimeter- and submillimeter-wave noise is continuous across a frequency range of about 60 GHz to about 400 GHz.
22. The apparatus of claim 18 wherein said millimeter- and submillimeter-wave noise is continuous across a frequency range of about 60 GHz to about 1 THz.
23. The apparatus of claim 18 further comprising a transmission structure coupled to an output of said frequency multiplier for directing said millimeter- and submillimeter-wave noise.
24. The apparatus of claim 18 wherein said microwave noise source is selected from the group consisting of: a diode noise source, a noise tube, and a thermal noise source.

25. The apparatus of claim 18 wherein said frequency multiplier is a semiconductor diode multiplier.
26. The apparatus of claim 18 wherein said apparatus is portable.
27. The apparatus of claim 18 further comprising one or more band-pass filters coupled to said frequency multiplier to create one or more discrete millimeter- and submillimeter-wave noise bands.
28. A spectrometer comprising:  
said apparatus of claim 18.
29. A method for generating millimeter and submillimeter-wave noise power comprising the steps of:  
producing microwave noise power;  
amplifying said microwave noise power into amplified noise power;  
adjusting said amplified noise power to a designated power level; and  
converting said adjusted noise power to millimeter- and submillimeter-wave noise through a frequency multiplier, wherein said designated power level is the maximum safe input level of said frequency multiplier.
30. The method of claim 29 further comprising testing millimeter- and submillimeter-wave components using said millimeter- and submillimeter-wave noise.
31. The method of claim 29 further comprising:  
directing said millimeter and submillimeter noise from said frequency multiplier into a Fourier Transform Spectrometer; and  
performing Fourier Transform Spectrometry on a test sample.
32. The method of claim 29 further comprising characterizing materials using said millimeter- and submillimeter-wave noise.
33. The method of claim 29 wherein said millimeter- and submillimeter-wave noise is continuous across the frequency range between about 60 to about 400 GHz.
34. The method of claim 29 wherein said millimeter- and submillimeter-wave noise is continuous across the frequency range between about 60 GHz to about 1 THz.

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